

1MHz, RRIO, CMOS Operational Amplifier

General Description

ET358 is low cost, voltage feedback amplifiers. The device can operate from 2.1V to 5.5V single supply, while consuming only 60μA quiescent current per Amplifier. It provides rail-to-rail input with a wide input common mode voltage range and rail-to-rail output voltage swing. This feature makes ET358 appropriate for buffering ASIC.

The ET358 offer a gain-bandwidth product of 1MHz and an ultra-low input bias current of 10pA. It is well suited for piezoelectric sensors, integrators and photodiode amplifiers.

The ET358 is designed into a wide range of applications, such as battery-powered instrumentation, safety monitoring, portable systems, and transducer interface circuits in low power systems.

It is available in SOP8/MSOP8 packages.

Features

Low offset voltage: 5 mV (MAX)
 Ultra-Low Input Bias Current: 10 pA

Unity-gain stable

Gain-Bandwidth Product: 1 MHz

Rail-to-rail input and output

Supply Voltage Range: 2.1V to 5.5V

Input Voltage Range: -0.1V to 5.6V with Vs=5.5V

Low Supply Current: 60µA/Amplifier

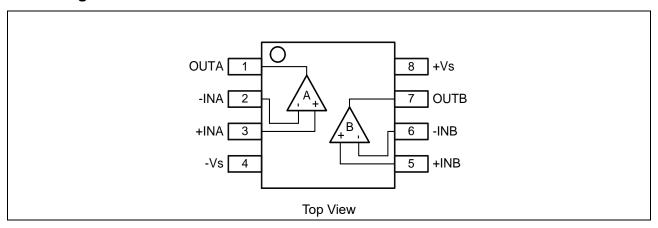
Applications

- ASIC Input or Output Amplifiers
- Piezoelectric Transducer Amplifiers
- Battery-Powered Equipment
- Portable Equipment
- Sensor Interfaces
- Medical Instrumentation
- Audio Outputs
- Smoke Detectors
- Notebook PCs

Device information

Part No.	Package	MSL
ET358M	SOP8	Level 3
ET358U	MSOP8	Level 3

Pin Configuration



Pin Function

Pin Number	Oah al	Descriptions	
ET358	Symbol		
1,7	OUT	Output	
4	-Vs	Negative supply	
3,5	+IN	Non-inverting input	
2,6	-IN	Inverting input	
8	+Vs	Positive supply	

Functional Description

Rail-to-Rail Input

When ET358 work at the power supply between 2.1V and 5.5V, the input common mode voltage range is from (-Vs) - 0.1V to (+Vs) + 0.1V.

Rail-to-Rail Output

The ET358 support rail-to-rail output operation. In single power supply application, for example, when $+V_S = 5V$, $-V_S = GND$, $100k\Omega$ load resistor is tied from OUT pin to $V_S/2$, the typical output swing range is from 0.005V to 4.997V.

Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

Parameter	Rating	Unit
Supply Voltage(+Vs) - (-Vs)	6	V
Common-mode Input Voltage	(-Vs)-0.3V to (+Vs)+0.3V	V
ESD (Human Body Model)	±4000	V
Storage Temperature Range	-65 to +150	°C
Junction Temperature Range	+150	°C
Operating Temperature Range	-40 to +125	°C

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
SOP8		Thermal Characteristics,	150	°C/W
Reja	MSOP8	Thermal Resistance, Junction-to-Air	210	°C/W

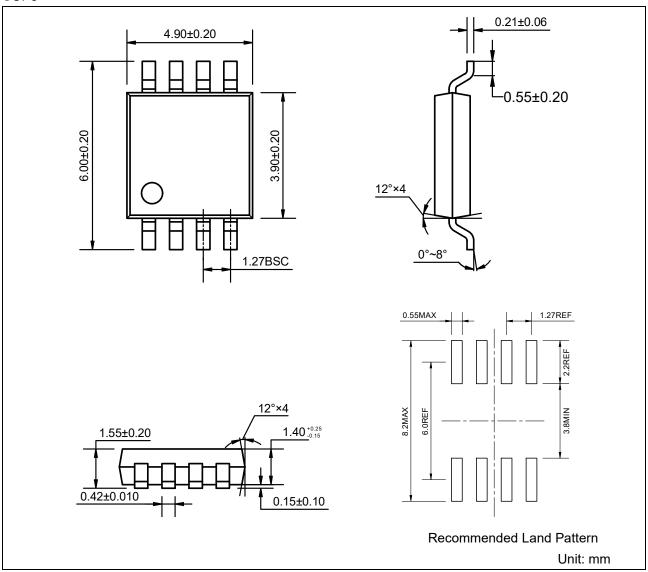
Electrical Characteristics

 V_{S} = +5 V, R_L=100k Ω connected to V_S/2, T_A = 25°C, unless otherwise noted.

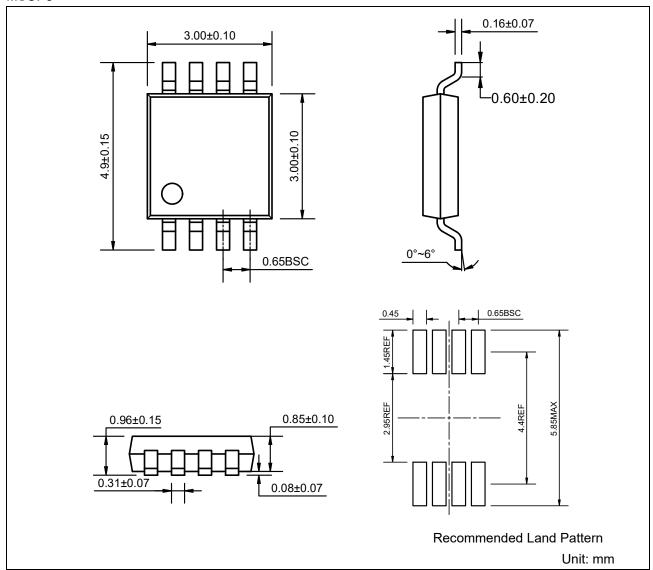
Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
INPUT CHA	RACTERISTICS						
Vos	Input offset Voltage	$V_{CM} = V_S/2$		0.8 5		mV	
I _B	Input Bias Current		10			pА	
Ios	Input Offset Current			10		pА	
V _{СМ}	Input Common Mode Voltage Range	V _S =5.5V	-0.1		5.6	V	
CMRR	Common-Mode Rejection Ratio	$V_S = 5.5 \text{ V},$ $V_{CM} = -0.1 \text{V to 4V}$	62	70		- dB	
		$V_S = 5.5 \text{ V},$ $V_{CM} = -0.1 \text{ V to } 5.6 \text{ V},$	55	68			
	0	R _L =5k Ω , V _{OUT} =0.1V to 4.9V	70	80			
Aol	Open-Loop Voltage Gain	R _L =100kΩ, V _{OUT} =0.035V to 4.965V	80	84	dB		
ΔV _{OS} /ΔT	Input Offset Voltage Drift			2.7		μV/°C	
OUTPUT CI	HARACTERISTICS						
Vон		R _L =100kΩ	4.980	4.997		V	
Vol	Output Voltage Swing from	R _L =100kΩ		5	20	mV	
Vон	Rail	R _L =10kΩ	4.970	4.992		V	
Vol		R _L =10kΩ		8	30	mV	
Isourse	Output Current	R _L =10Ω to V _S /2	60	85		mA	
Isink	Output Current	NL-1022 to VS/2	60	75		mA	
POWER SU	PPLY						
	Operating Voltage Range		2.1		5.5	V	
PSRR	Power Supply Rejection Ratio	V_S =2.5V to 5.5V, V_{CM} =0.5V	60	82		dB	
ΙQ	Quiescent Current/Amplifier	V _S =5V, V _{CM} =2.5V		60	85	μA	
DYNAMIC F	PERFORMANCE						
GBP	Gain-Bandwith Product			1		MHz	
SR	Slew Rate	G=+1, 2 V Output Step		0.6		V/µs	
ts	Setting Time to 0.1%	G=+1, 2 V Output Step		5.3		μs	
NOISE PER	FORMANCE						
En	Input voltage noise (peak to peak)	f = 0.1 Hz to 10 Hz		6		μV _{PP}	
_	Input Voltage Noise	f=1kHz		25		nV/√Hz	
en	Density	f=10kHz		20		nV/√Hz	

Package Dimension

SOP8



MSOP8



Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2024-01-31	Official version	Chenzx	Wanggp	Liujy
1.1	2024-12-03	Add I _Q test condition	Yinp	Chenh	Liujy